

PHOTON IS OUR BUSINESS

Si photodiode with preamp

S9269 S

S9270

Photodiode and preamp integrated with feedback resistance and capacitance

S9269 and S9270 are low-noise photosensors consisting of a Si photodiode, op amp, and feedback resistance and capacitance, all integrated into same package with a surface size equal to our standard ceramic packages. These photosensors are ideal for a wide range of photometric applications including analytical equipment and measurement equipment. The active area of the photodiode is internally connected to the GND terminal making it highly resistant to EMC noise. Combinations with various photodiodes such as UV sensitivity enhanced type, IR sensitivity suppressed type and IR sensitivity enhanced type are also available. (Custom order products)

Applications

Precision photometry

General-purpose optical measurement

Features

- Si photodiode for visible to near IR Si precision photometry
- Small package S9269: 10.1 × 8.9 × 40 ^t mm S9270: 16.5 × 15.0 × 4.15 ^t mm
- Active area S9269: 5.8 × 5.8 mm S9270: 10 × 10 mm
- FET input operational amplifier with low power dissipation
- **Built-in Rf=1 G** Ω , Cf=5 pF
- Low noise and NEP

- Absolute maximum ratings (Ta=25 °C)

Parameter	Symbol	Value	Unit
Supply voltage (op amp)	Vcc	±20	V
Power dissipation	Р	500	mW
Operating temperature	Topr	-20 to +60	°C
Storage temperature	Tstg	-20 to +80	°C

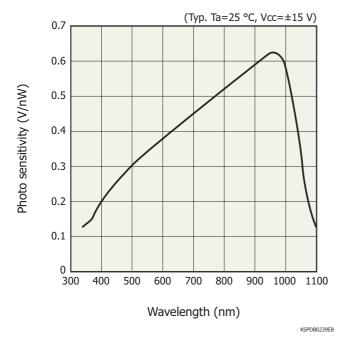
Note: Absolute maximum ratings are the values that must not be exceeded at any time. If even one of the absolute maximum ratings is exceeded even for a moment, the product quality may be impaired. Always be sure to use the product within the absolute maximum ratings.

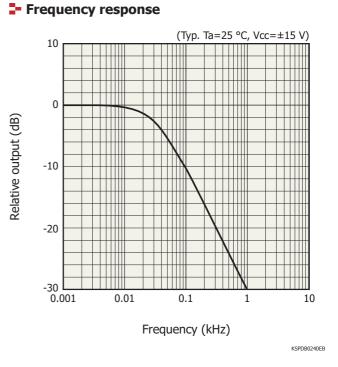
■ Electrical and optical characteristics (Ta=25 °C, Vcc=±15 V, RL=1 MΩ)

Parameter	Symbol	Condition	S9269			S9270			Unit
			Min.	Тур.	Max.	Min.	Тур.	Max.	
Spectral response range	λ		-	340 to 1100	-	-	340 to 1100	-	nm
Peak sensitivity wavelength	λp		-	960	-	-	960	-	nm
Feedback resistance (built-in) *	Rf		-	1	-	-	1	-	GΩ
Feedback capacitance (built-in) *	Cf		-	5	-	-	5	-	pF
Photo sensitivity	S	λ=λp	0.5	0.62	-	0.5	0.62	-	V/nW
Output noise voltage	Vn	Dark state, f=10 Hz	-	7.3	-	-	9.7	-	μVrms/Hz ^{1/2}
		Dark state, f=20 Hz	-	6.5	-	-	9.1	-	
Noise equivalent power	NEP	λ=λp, f=10 Hz	-	12	-	-	16	-	fW/Hz ^{1/2}
		$\lambda = \lambda p$, f=20 Hz	-	12	-	-	17	-	
Output offset voltage	Vos	Dark state	-	±4	-	-	±4	-	mV
Cut-off frequency	fc	-3 dB	-	32	-	-	32	-	Hz
Output voltage swing	Vo	RL=10 kΩ	-	13	-	-	13	-	V
Supply current	Icc	Dark state	-	0.3	0.6	-	0.3	0.6	mA

* Custom devices available with different Rf, Cf, etc.

Spectral response

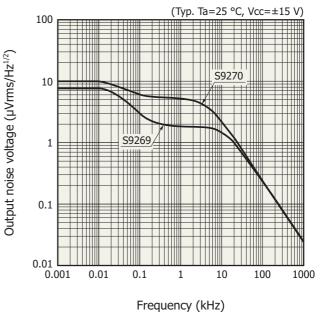




NEP vs. frequency

(Typ. Ta=25 °C, Vcc=±15 V) 10⁵ 10⁴ S9270 NEP (fW/Hz^{1/2}) 10³ 10² S9269 10¹ 10⁰ 0.001 0.01 0.1 10 100 1000 1 Frequency (kHz) KSPDB0241EA

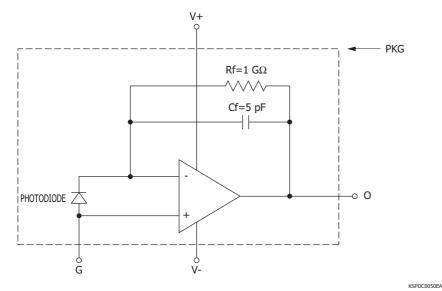
Output noise voltage vs. frequency



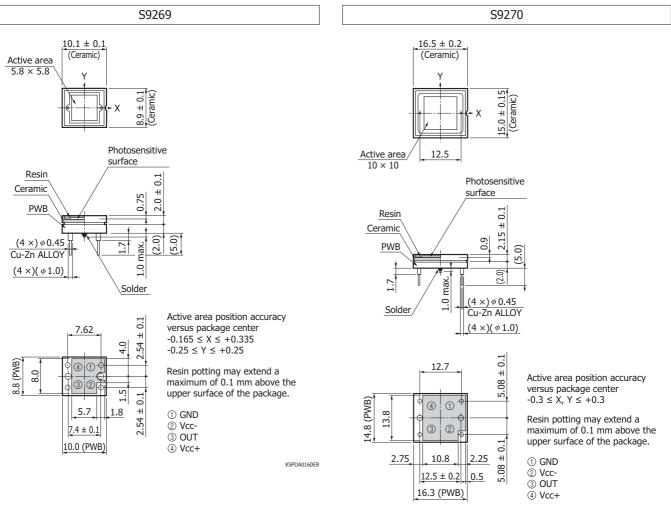
KSPDB0242EA



Application circuit example



Dimensional outline (unit: mm, tolerance unless otherwise noted: ±0.2)



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KSPDA0161EB

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Precautions for use

ESD

S9269, S9270 may be damaged or their performance may deteriorate by such factors as electro static discharge from the human body, surge voltages from measurement equipment, leakage voltages from soldering irons and packing materials, etc. As a countermeasure against electro static discharge, the device, operator, work place and measuring jigs must all be set at the same potential. The following precautions must be observed during use:

- To protect the device from electro static discharge which accumulate on the operator or the operator's clothes, use a wrist strap or similar tools to ground the operator's body via a high impedance resistor (1 M Ω).
- · A semiconductive sheet (1 M Ω to 100 M Ω) should be laid on both the work table and the floor in the work area.
- \cdot When soldering, use an electrically grounded soldering iron with an isolation resistance of more than 10 M Ω .
- · For containers and packing, use of a conductive material or aluminum foil is effective. When using an antistatic material, use one with a resistance of 0.1 M Ω /cm² to 1 G Ω /cm².

• Wiring

If electric current or voltage is applied in reverse polarity to an electronic device such as a preamplifier, this can degrade device performance or destroy the device. Always check the wiring and dimensional outline to avoid misconnection.

Information described in this material is current as of October, 2011.

Product specifications are subject to change without prior notice due to improvements or other reasons. Before assembly into final products, please contact us for the delivery specification sheet to check the latest information.

The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use.

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